

SCHOTTKY BARRIER RECTIFIERS

VOLTAGE RANGE: 30 - 100 V
CURRENT: 60 A

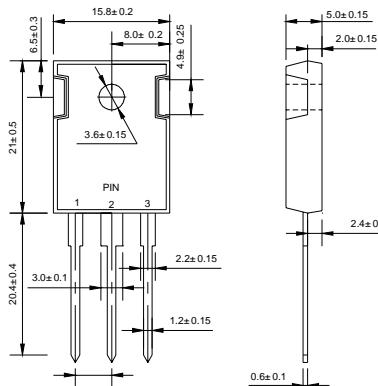
FEATURES

- ◇ High surge capacity.
- ◇ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- ◇ Metal silicon junction, majority carrier conduction.
- ◇ High current capacity, low forward voltage drop.
- ◇ Guard ring for over voltage protection.

MECHANICAL DATA

- ◇ Case: JEDEC TO-3P, molded plastic body
- ◇ Terminals: Solderable per MIL-STD-750, Method 2026
- ◇ Polarity: As marked
- ◇ Position: Any
- ◇ Weight: 0.223 ounce, 6.3 grams

TO-3P(TO-247AD)



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

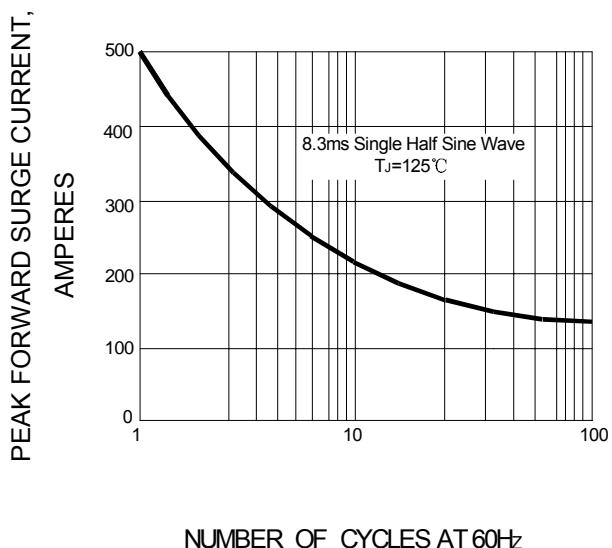
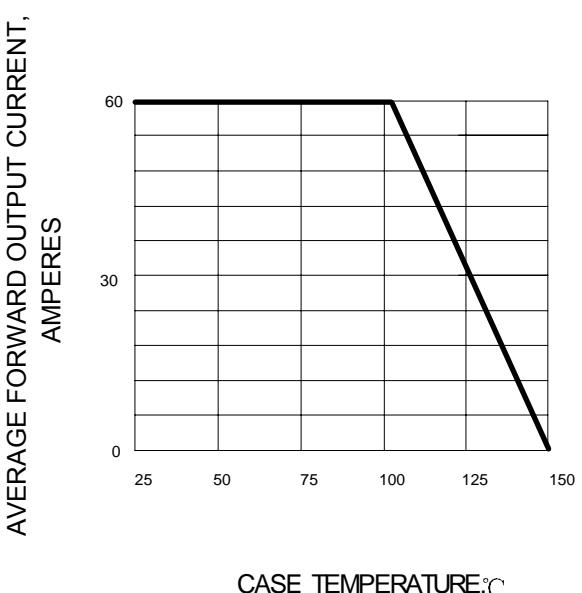
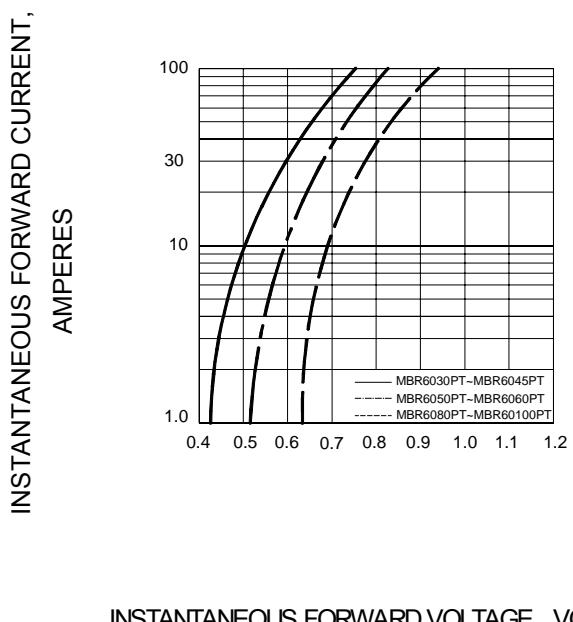
Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

		MBR 6030PT	MBR 6035PT	MBR 6040PT	MBR 6045PT	MBR 6050PT	MBR 6060PT	MBR 6080PT	MBR 60100PT	UNITS				
Maximum recurrent peak reverse voltage	V_{RRM}	30	35	40	45	50	60	80	100	V				
Maximum RMS Voltage	V_{RMS}	21	25	28	32	35	42	56	70	V				
Maximum DC blocking voltage	V_{DC}	30	35	40	45	50	60	80	100	V				
Maximum average forward total device rectified current @ $T_c = 105^\circ C$	$I_{F(AV)}$	60								A				
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	I_{FSM}	500								A				
Maximum forward voltage @ $I_F=30A, T_c=25^\circ C$	V_F	0.62			0.75		0.85		V					
Maximum reverse current @ $T_A=25^\circ C$ at rated DC blocking voltage @ $T_A=100^\circ C$	I_R	20						mA						
Maximum thermal resistance (Note2)	$R_{\theta JC}$	200												
Operating junction temperature range	T_J	-55 ---- +150								°C				
Storage temperature range	T_{STG}	-55 ---- +150								°C				

NOTE: 1. Thermal resistance from junction to case.

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FIG.1 – PEAK FORWARD SURGE CURRENT**FIG.2 – FORWARD DERATING CURVE****FIG.3 – TYPICAL FORWARD CHARACTERISTIC****FIG.4 – TYPICAL REVERSE CHARACTERISTIC**